

## NPN Epitaxial Silicon Transistor

## FJL4315, 2SC5200

### **Features**

High Current Capability: I<sub>C</sub> = 17 A
High Power Dissipation: 150 W

• High Frequency: 30 MHz

• High Voltage:  $V_{CEO} = 250 \text{ V}$ 

• Wide S.O.A. for Reliable Operation

• Excellent Gain Linearity for Low THD

• Complement to 2SA1943 / FJL4215

• Thermal and Electrical Spice Models are Available

• Same Transistor is also Available in:

◆ TO3P Package, 2SC5242 / FJA4313 : 130 Watts

TO220 Package, FJP5200: 80 WattsTO220F Package, FJPF5200: 50 Watts

• These Devices are Pb-Free and are RoHS Compliant

### **Applications**

• High-Fidelity Audio Output Amplifier

• General Purpose Power Amplifier

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Ratings	Units
Collector-Base Voltage	BV <sub>CBO</sub>	250	V
Collector-Emitter Voltage	BV <sub>CEO</sub>	250	V
Emitter-Base Voltage	BV <sub>EBO</sub>	5	V
Collector Current (DC)	I <sub>C</sub>	17	Α
Base Current	Ι <sub>Β</sub>	1.5	Α
Total Device Dissipation (T <sub>C</sub> = 25°C) Derate Above 25°C	$P_{D}$	150 1.04	W W/°C
Junction and Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>	<b>−50</b> ~ <b>+150</b>	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS (Note 1)

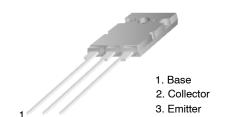
(T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Max.	Units
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.83	°C/W

1. Device mounted on minimum pad size.

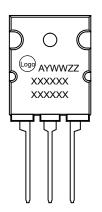
### **h**FE CLASSIFICATION

Classification	R	0
h <sub>FE1</sub>	55 ~ 110	80 ~ 160



TO-264-3LD CASE 340CA

#### MARKING DIAGRAM



A = Assembly Location

YWW = Date Code ZZ = Assembly Lot

xxxxx = Specific Device Code (J4315O or C5200O)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

### FJL4315, 2SC5200

### **ELECTRICAL CHARACTERISTICS** (Note 2) (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 5 \text{ mA}, I_E = 0$	250			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, R_{BE} = \infty$	250			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 5 \text{ mA}, I_C = 0$	5			V
I <sub>CBO</sub>	Collector Cut-Off Current	V <sub>CB</sub> = 230 V, I <sub>E</sub> = 0			5.0	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 5 \text{ V}, I_{C} = 0$			5.0	μΑ
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	55		160	
h <sub>FE2</sub>	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 7 \text{ A}$	35	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8 A, I <sub>B</sub> = 0.8 A		0.4	3.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 7 \text{ A}$		1.0	1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1 MHz		200		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width =  $20 \mu s$ , Duty Cycle  $\leq 2\%$ 

### **ORDERING INFORMATION**

Part Number	Marking	Package	Shipping	Remarks
2SC5200OTU	C5200O	TO-264-3LD (Pb-Free)	375 Units / Tube	h <sub>FE1</sub> O grade
FJL4315OTU	J4315O	TO-264-3LD (Pb-Free)	375 Units / Tube	h <sub>FE1</sub> O grade

### **TYPICAL CHARACTERISTICS**

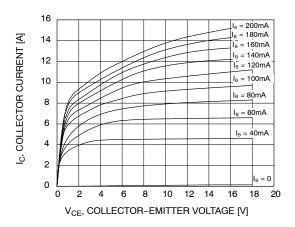


Figure 1. Static Characteristic

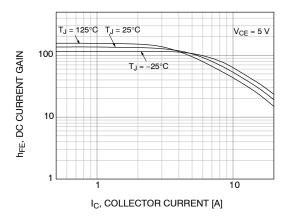


Figure 3. DC Current Gain (O Grade)

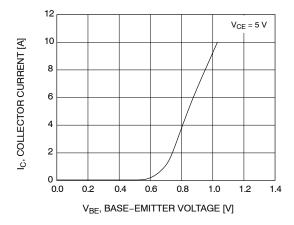


Figure 5. Base-Emitter On Voltage

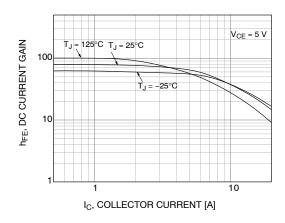


Figure 2. DC Current Gain (R Grade)

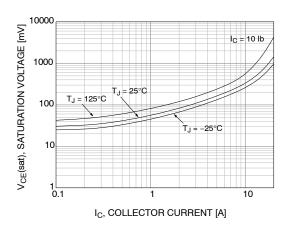


Figure 4. Collector-Emitter Saturation Voltage

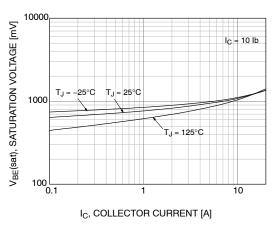


Figure 6. Base-Emitter Saturation Voltage

### FJL4315, 2SC5200

### **TYPICAL CHARACTERISTICS**

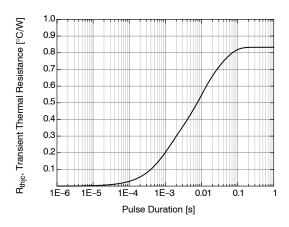


Figure 7. Power Derating

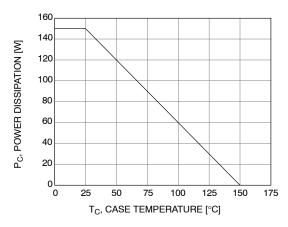


Figure 9. Power Derating

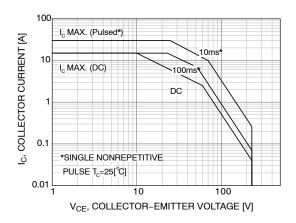
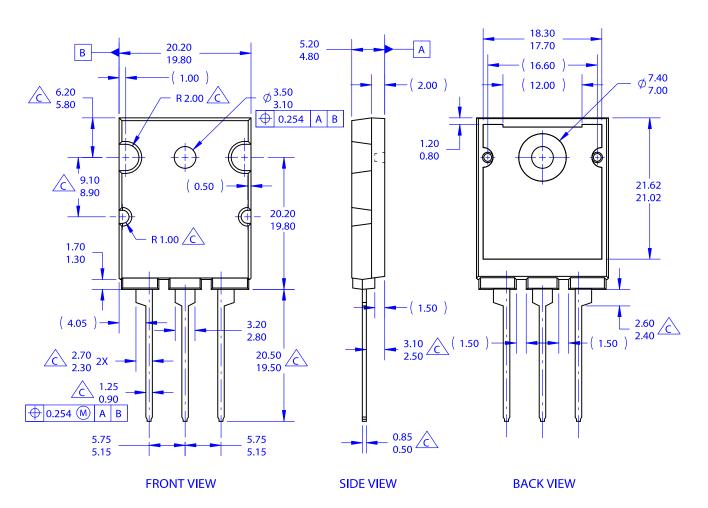


Figure 8. Safe Operating Area

TO-264-3LD CASE 340CA ISSUE O

**DATE 31 OCT 2016** 



# 3.70 3.30 4.80 BOTTOM VIEW

**NOTES:** 

A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA.

B. ALL DIMENSIONS ARE IN MILLIMETERS.

D. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.

E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

DOCUMENT NUMBER:	98AON13860G	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-264-3LD		PAGE 1 OF 1	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales